NSN 5962-01-335-3514

Memory Microcircuit - Page 1 of 1



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Features Provided:
Monolithic and programmable and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Terminal Surface Treatment:
Solder
Memory Device Type:
Rom
Terminal Type And Quantity:
28 leadless
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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